# MM54HC266A/MM74HC266A Quad 2-Input Exclusive NOR Gate (Open Drain)

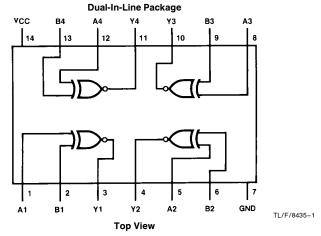
## **General Description**

This exclusive NOR gate utilizes advanced silicon-gate CMOS technology to achieve operating speeds similar to equivalent LS-TTL gates while maintaining the low power consumption and high noise immunity characteristic of standard CMOS integrated circuits. These gates are fully buffered and have a fanout of 10 LS-TTL loads. The MM54HC/ MM74HC logic family is functionally as well as pin out compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to  $V_{CC}$  and ground.

#### **Features**

- Typical propagation delay: 9 ns
- Wide operating voltage range: 2-6V
- Low input current: 1 µA maximum
- Low quiescent current: 20 µA maximum (74 Series)
- Output drive capability: 10 LS-TTL loads
- Open drain outputs

## **Connection Diagram**



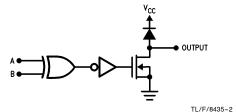
Order Number MM54HC266A or MM74HC266A

### **Truth Table**

Inputs		Outputs
Α	В	Y
L	L	Z
L	Н	L
Н	L	L
Н	Н	Z

 $Y = \overline{A \oplus B} = AB + \overline{AB}$ 

# **Logic Diagram**



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## Absolute Maximum Ratings (Notes 1 & 2) If Military/Aerospace specified devices are required,

please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V <sub>CC</sub> )	-0.5 to $+7.0$ V
DC Input Voltage (V <sub>IN</sub> )	$-1.5$ to $V_{CC} + 1.5V$
DC Output Voltage (V <sub>OUT</sub> )	$-0.5$ to $V_{CC} + 0.5V$
Clamp Diode Current (I <sub>IK</sub> , I <sub>OK</sub> )	$\pm$ 20 mA
DC Output Current, per pin (IOUT)	$\pm$ 25 mA
DC V <sub>CC</sub> or GND Current, per pin (I <sub>CC</sub> )	$\pm$ 50 mA
Storage Temperature Range (T <sub>STG</sub> )	$-65^{\circ}\text{C to } + 150^{\circ}\text{C}$

Power Dissipation (PD)

(Note 3) 600 mW S.O. Package only 500 mW 260°C

Lead Temp. (T<sub>L</sub>) (Soldering 10 seconds)

Operating Conditions								
	Min	Max	Units					
Supply Voltage (V <sub>CC</sub> )	2	6	V					
DC Input or Output Voltage $(V_{IN}, V_{OUT})$	0	$V_{CC}$	V					
Operating Temp. Range (T <sub>A</sub> )								
MM74HC	-40	+85	°C					
MM54HC	-55	+125	°C					
Input Rise or Fall Times								
$(t_r, t_f)$ $V_{CC} = 2.0V$		1000	ns					
V <sub>CC</sub> =4.5V		500	ns					
$V_{CC} = 6.0V$		400	ns					

### **DC Electrical Characteristics** (Note 4)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> = 25°C		74HC T <sub>A</sub> = -40 to 85°C	54HC T <sub>A</sub> = -55 to 125°C	Units
				Тур		Guaranteed	Limits	
V <sub>IH</sub>	Minimum High Level		2.0V		1.5	1.5	1.5	٧
	Input Voltage		4.5V		3.15	3.15	3.15	V
			6.0V		4.2	4.2	4.2	V
$V_{IL}$	Maximum Low Level		2.0V		0.5	0.5	0.5	V
	Input Voltage**		4.5V		1.35	1.35	1.35	V
			6.0V		1.8	1.8	1.8	V
V <sub>OH</sub>	Minimum High Level	V <sub>IN</sub> =V <sub>IH</sub> or V <sub>II</sub>						
0	Output Voltage	I <sub>OUT</sub>  ≤20 μA	2.0V	2.0	1.9	1.9	1.9	V
			4.5V	4.5	4.4	4.4	4.4	V
			6.0V	6.0	5.9	5.9	5.9	V
		V <sub>IN</sub> =V <sub>IL</sub>						
		I <sub>OUT</sub>  ≤4.0 mA	4.5V	4.2	3.98	3.84	3.7	V
		I <sub>OUT</sub>  ≤5.2 mA	6.0V	5.7	5.48	5.34	5.2	V
VOI	Maximum Low Level	V <sub>IN</sub> =V <sub>IH</sub> or V <sub>II</sub>						
OL.	Output Voltage	I <sub>OUT</sub>  ≤20 μA	2.0V	0	0.1	0.1	0.1	V
		,	4.5V	0	0.1	0.1	0.1	V
			6.0V	0	0.1	0.1	0.1	V
		V <sub>IN</sub> =V <sub>IH</sub> or V <sub>II</sub>						
		I <sub>OUT</sub>  ≤4.0 mA	4.5V	0.2	0.26	0.33	0.4	V
		I <sub>OUT</sub>  ≤5.2 mA	6.0V	0.2	0.26	0.33	0.4	V
I <sub>IN</sub>	Maximum Input Current	V <sub>IN</sub> =V <sub>CC</sub> or GND	6.0V		±0.1	±1.0	±1.0	μΑ
Icc	Maximum Quiescent Supply Current	V <sub>IN</sub> =V <sub>CC</sub> or GND I <sub>OUT</sub> =0 μA	6.0V		2.0	20	40	μА
l <sub>OZ</sub>	Maximum TRI-STATE® Leakage Current	V <sub>IN</sub> =V <sub>IL</sub> or V <sub>IH</sub> V <sub>OUT</sub> =V <sub>CC</sub> or GND	6.0V		±0.5	±5.0	± 10.0	μΑ

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: -12 mW/°C from 65°C to 85°C; ceramic "J" package: -12 mW/°C from 100°C to 125°C.

Note 4: For a power supply of 5V  $\pm$  10% the worst case output voltages ( $V_{OH}$ , and  $V_{OL}$ ) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V<sub>IH</sub> and V<sub>IL</sub> occur at V<sub>CC</sub>= 5.5V and 4.5V respectively. (The V<sub>IH</sub> value at 5.5V is 3.85V.) The worst case leakage current (I<sub>IN</sub>, I<sub>CC</sub>, and I<sub>OZ</sub>) occur for CMOS at the higher voltage and so the 6.0V values should be used.

<sup>\*\*</sup>V<sub>IL</sub> limits are currently tested at 20% of V<sub>CC</sub>. The above V<sub>IL</sub> specification (30% of V<sub>CC</sub>) will be implemented no later than Q1, CY'89.

## AC Electrical Characteristics $V_{CC}=5V,\,T_A=25^{\circ}C,\,C_L=15$ pF, $t_r=t_f=6$ ns

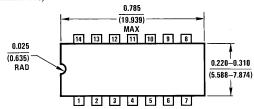
Symbol	Parameter	Conditions	Тур	Guaranteed Limit	Units
t <sub>PLZ</sub> , t <sub>PZL</sub>	Maximum Propagation Delay		12	20	ns

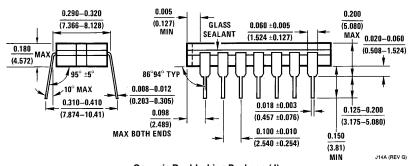
## AC Electrical Characteristics $V_{CC}=2.0V$ to 6.0V, $C_L=50$ pF, $t_r=t_f=6$ ns (unless otherwise specified)

Symbol	Parameter	Conditions	v <sub>cc</sub>	T <sub>A</sub> =25°C		74HC T <sub>A</sub> = -40 to 85°C	54HC T <sub>A</sub> = -55 to 125°C	Units	
				Typ Guaranteed Limits					
t <sub>PLZ</sub> , t <sub>PZL</sub>	Maximum Propagation Delay		2.0V 4.5V 6.0V	60 12 10	120 24 20	151 30 26	179 36 30	ns ns ns	
t <sub>THL</sub>	Maximum Output Fall Time		2.0V 4.5V 6.0V	30 8 7	75 15 13	95 19 16	110 22 19	ns ns ns	
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	(per gate)		25				pF	
C <sub>IN</sub>	Maximum Input Capacitance			5	10	10	10	pF	
C <sub>OUT</sub>	Maximum Three State Output Capacitance Output in TRI-STATE				10	10	10	pF	

Note 5:  $C_{PD}$  determines the no load dynamic power consumption,  $P_D = C_{PD} \ V_{CC}^2 \ f + I_{CC} \ V_{CC}$ , and the no load dynamic current consumption,  $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$ .

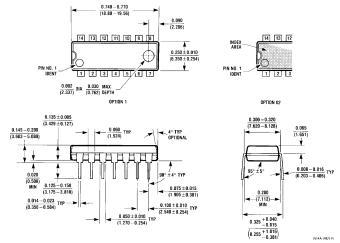
#### Physical Dimensions inches (millimeters)





Ceramic Dual-In-Line Package (J) Order Number MM54HC266AJ NS Package Number J14A

## Physical Dimensions inches (millimeters) (Continued)



Molded Dual-In-Line Package (N) Order Number MM74HC266AN NS Package Number N14A

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